

RAPID COMMUNICATIONS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

- Phonon thermal conductivity and stripe correlations in $\text{La}_{2-x}\text{Sr}_x\text{NiO}_4$ and $\text{Sr}_{1.5}\text{La}_{0.5}\text{MnO}_4$ R10 397
C. Hess, B. Büchner, M. Hücker, R. Gross, and S-W. Cheong
- Absolute three-dimensional photonic band gap in the infrared regime in woven structures R10 401
Ya-Chih Tsai, John B. Pendry, and Kenneth W.-K. Shung
- Fermiology of a one-dimensional heavy-electron metal R10 405
C. Gröber and R. Eder
- Correlation effects in the low-energy region of nickel photoemission spectra R10 409
F. Manghi, V. Bellini, J. Osterwalder, T. J. Kreutz, P. Aebi, and C. Arcangeli

Semiconductors II: surfaces, interfaces, microstructures, and related topics

- High-resolution core-level study of initial oxygen adsorption on Si(001): Surface stoichiometry and anomalous Si 2p core-level shifts R10 413
H. W. Yeom, H. Hamamatsu, T. Ohta, and R. I. G. Uhrberg
- Pulsed-magnetic-field measurements of Hall potential oscillations in $\alpha\text{-(BEDT-TTF)}_2\text{TIHg(SCN)}_4$ within the quantum Hall regime R10 417
M. M. Honold, N. Harrison, J. Singleton, M.-S. Nam, S. J. Blundell, C. H. Mielke, M. V. Kartsovnik, and N. D. Kushch
- Spin coherence in semiconductor quantum dots R10 421
J. A. Gupta, D. D. Awschalom, X. Peng, and A. P. Alivisatos
- Comparative study of the negatively and positively charged excitons in GaAs quantum wells R10 425
Shmuel Glasberg, Gleb Finkelstein, Hadas Shtrikman, and Israel Bar-Joseph
- Stationary coherence in semiconductor microcavities R10 429
G. Cassaboïs, A. L. C. Triques, D. Larousserie, C. Delalande, Ph. Roussignol, P. Senellart-Mardon, J. Bloch, V. Thierry-Mieg, and R. Planel
- Conductance quantization in V-groove quantum wires R10 433
D. Kaufman, Y. Berk, B. Dwir, A. Rudra, A. Palevski, and E. Kapon
- g -factor dependence of the evolution of magneto-optical spectra with the density of quasi-two-dimensional electrons in $\text{Cd}_{1-x}\text{Mn}_x\text{Te}/\text{Cd}_{1-y}\text{Mg}_y\text{Te}$ heterostructures R10 437
T. Wojtowicz, M. Kutrowski, G. Karczewski, J. Kossut, F. J. Teran, and M. Potemski
- Statistics of the Coulomb-blockade peak spacings of a silicon quantum dot R10 441
F. Simmel, David Abusch-Magder, D. A. Wharam, M. A. Kastner, and J. P. Kotthaus



Born approximation versus the exact approach to carrier-impurity collisions in a one-dimensional semiconductor: Impact on the mobility	R10 445
Martin Moško and Pavel Vagner	

Surface physics, low-dimensional systems, and related topics

Direct observation of sulfur dimers in alkanethiol self-assembled monolayers on Au(111)	R10 449
G. Jonathan Kluth, Carlo Carraro, and Roya Maboudian	
Atomic structures and phase transitions of Si(113) reconstructed surfaces: Kikuchi electron holography studies	R10 453
C. Y. Chang, Y. C. Chou, and C. M. Wei	
Universality of electron correlations in conducting carbon nanotubes	R10 457
Arkadi A. Odintsov and Hideo Yoshioka	

ARTICLES**Electronic structure: wide-band, narrow-band, and strongly correlated systems**

Density-functional correction of random-phase-approximation correlation with results for jellium surface energies	10 461
Stefan Kurth and John P. Perdew	
Absence of U 5 <i>f</i> band states in resonant photoemission spectra of UPd ₂ Al ₃	10 469
Shin-ichi Fujimori, Yasuharu Saito, Masaharu Seki, Koji Tamura, Munenori Mizuta, Ken-ichiro Yamaki, Ken Sato, Akinori Tanaka, Noriaki Sato, Shoji Suzuki, Shigeru Sato, Tetsuo Okane, Takemi Komatsubara, Yasuhisa Tezuka, Shik Shin, and Takehiko Ishii	
Two-dimensional weakly interacting Fermi gas in a magnetic field: Level splitting	10 473
Alexei Kolesnikov	
Pseudojellium, ideal metals, and stabilized jellium	10 485
Herbert B. Shore and James H. Rose	
Density-matrix renormalization group for a gapless system of free fermions	10 493
Martin Andersson, Magnus Boman, and Stellan Östlund	
Augmented Fourier components method for constructing the crystal potential in self-consistent band-structure calculations	10 504
E. E. Krasovskii, F. Starrost, and W. Schattke	
Three-dimensional electron momentum density of aluminum by ($\gamma, e\gamma$) spectroscopy	10 512
C. Metz, Th. Tschentscher, P. Suortti, A. S. Kheifets, D. R. Lun, T. Sattler, J. R. Schneider, and F. Bell	
Crystal Hartree-Fock calculations for La ₂ NiO ₄ and La ₂ CuO ₄	10 521
Yen-Sheng Su, T. A. Kaplan, S. D. Mahanti, and J. F. Harrison	
Electronic structure of yttrium aluminum garnet (Y ₃ Al ₅ O ₁₂)	10 530
Yong-Nian Xu and W. Y. Ching	
Metallic properties of the ternary fullerenes ABa ₂ C ₆₀ (A=K,Rb,Cs)	10 536
K.-F. Thier, C. Goze, M. Mehring, F. Rachdi, T. Yildirim, and J. E. Fischer	
Nearly universal crossing point of the specific heat curves of Hubbard models	10 541
N. Chandra, M. Kollar, and D. Vollhardt	
Electronic correlations on the verge of the Mott transition in La _{1-x} Sr _x TiO ₃ by ^{47/49} Ti and ¹³⁹ La nuclear magnetic resonance	10 550
Y. Furukawa, I. Okamura, K. Kumagai, T. Goto, T. Fukase, Y. Taguchi, and Y. Tokura	
Muonium formation via electron transport in solid nitrogen	10 559
V. Storchak, J. H. Brewer, G. D. Morris, D. J. Arseneau, and M. Senba	
Electronic structure of silicon carbide polytypes studied by soft x-ray spectroscopy	10 573
J. Lüning, S. Eisebitt, J.-E. Rubensson, C. Ellmers, and W. Eberhardt	
Geometric and electronic structure of vanadium pentoxide: A density functional bulk and surface study	10 583
A. Chakrabarti, K. Hermann, R. Druzinic, M. Witko, F. Wagner, and M. Petersen	
Role of the intrinsic surface state in the decay of image states at a metal surface	10 591
J. Osma, I. Sarriá, E. V. Chulkov, J. M. Pitarke, and P. M. Echenique	

(Continued)

Strong tunneling and Coulomb blockade in a single-electron transistor	10 599
D. Chouvaev, L. S. Kuzmin, D. S. Golubev, and A. D. Zaikin	

Semiconductors I: bulk

Defect characterization in electron-irradiated 6H-SiC by positron annihilation	10 603
A. Polity, S. Huth, and M. Lausmann	
Distribution of gap states in amorphous selenium thin films	10 607
H.-Z. Song, G. J. Adriaenssens, E. V. Emelianova, and V. I. Arkhipov	
Phonons in $\text{Ge}_{1-x}\text{Si}_x$ bulk crystals	10 614
M. Franz, K. F. Dombrowski, H. Rücker, B. Dietrich, K. Pressel, A. Barz, U. Kerat, P. Dold, and K. W. Benz	
Photoinduced electron transfer from conjugated polymers to CdSe nanocrystals	10 622
D. S. Ginger and N. C. Greenham	
Transient heat transport by carriers and phonons in semiconductors	10 630
A. F. Carballo Sánchez, G. González de la Cruz, Yu G. Gurevich, and G. N. Logvinov	
T-matrix approach to equilibrium and nonequilibrium carrier-carrier scattering in semiconductors	10 639
D. O. Gericke, S. Kosse, M. Schlanges, and M. Bonitz	
Photoconductivity of sexithiophene single crystals	10 651
Gilles Horowitz, Fayçal Kouki, Pierre Valat, Philippe Delannoy, and Joseph Roussel	

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Ge/GaAs(001) interface formation investigated by reflectance anisotropy spectroscopy	10 657
V. Emiliani, A. I. Shkrebtii, C. Goletti, A. M. Frisch, B. O. Fimland, N. Esser, and W. Richter	
Atomic placement of Al on the GaAs {001} $c(4\times 4)$ reconstruction determined by angle-resolved secondary-ion mass spectrometry	10 662
Stephen H. Goss, Gregory L. Fisher, Prasad B. S. Kodali, Barbara J. Garrison, and Nicholas Winograd	
ZnTe/Zn(S,Te) superlattices: A relaxation study by x-ray diffraction and reflectometry	10 670
M. Korn, M. Li, S. Tiong-Palisoc, M. Rauch, and W. Faschinger	
Electron-paramagnetic-resonance study of the (100)Si/Si ₃ N ₄ interface	10 677
P. Aubert, H. J. von Bardeleben, F. Delmotte, J. L. Cantin, and M. C. Hugon	
Modeling the phase-change processes in pulsed laser-irradiated InSb	10 685
R. Černý, V. Cháb, G. Ivlev, E. Gatskevich, and P. Přikryl	
Transport properties of $\text{Bi}_{1-x}\text{Sb}_x$ alloy thin films grown on CdTe(111)B	10 691
Sunglae Cho, Antonio DiVenere, George K. Wong, John B. Ketterson, and Jerry R. Meyer	
X-ray reflectivity measurement of δ -doped erbium profile in silicon molecular-beam epitaxial layer	10 697
Jun Wan, Z. M. Jiang, D. W. Gong, Y. L. Fan, C. Sheng, Xun Wang, Q. J. Jia, W. L. Zheng, and X. M. Jiang	
Characteristics of sub-keV atom-Si(111) surface collisions	10 701
Magnus Hedström and Hai-Ping Cheng	
Fluctuation of conductance-peak spacings in large semiconductor quantum dots	10 707
Yshai Avishai, Daniel Berend, and Richard Berkovits	
Si spreading in lattice-matched $\text{In}_{0.53}\text{Ga}_{0.47}\text{As}$ grown by molecular-beam epitaxy	10 712
E. Skuras, A. R. Long, B. Vögele, M. C. Holland, C. R. Stanley, E. A. Johnson, M. van der Burgt, H. Yaguchi, and J. Singleton	
Interacting electrons in polygonal quantum dots	10 719
C. E. Creffield, Wolfgang Häusler, J. H. Jefferson, and Sarben Sarkar	
Random telegraph noise in photoluminescence from individual self-assembled quantum dots	10 725
M-E. Pistol, P. Castrillo, D. Hessman, J. A. Prieto, and L. Samuelson	

Collective charge-density excitations in two-component one-dimensional quantum plasmas: Phase-fluctuation-mode dispersion and spectral weight in semiconductor quantum-wire nanostructures	10 730
S. Das Sarma and E. H. Hwang	
Conductance oscillations in tunnel-coupled quantum dots in the quantum Hall regime	10 744
C. Livermore, D. S. Duncan, R. M. Westervelt, K. D. Maranowski, and A. C. Gossard	
Quantum open-systems approach to current noise in resonant tunneling junctions	10 748
He Bi Sun and G. J. Milburn	
Bulk and edge correlations in the compressible half-filled quantum Hall state	10 757
Milica V. Milovanović and Efrat Shimshoni	
Effect of charged donor correlation and Wigner liquid formation on the transport properties of a two-dimensional electron gas in modulation δ -doped heterojunctions	10 769
R. Grill and G. H. Döhler	
Charging and heating effects in a system of coupled single-electron tunneling devices	10 778
V. A. Krupenin, S. V. Lotkhov, H. Scherer, Th. Weimann, A. B. Zorin, F.-J. Ahlers, J. Niemeyer, and H. Wolf	
Intersubband transitions in InAs/GaSb semimetallic superlattices	10 785
A. J. L. Poulter, M. Lakrimi, R. J. Nicholas, N. J. Mason, and P. J. Walker	
Bulk and interface Al 2 <i>p</i> core excitons in GaAs/AlAs/GaAs heterostructures	10 792
A. Agui, S. Shin, C. Wu, K. Shiba, and K. Inoue	
Polarization-dependent time- and angle-resolved laser photoemission study of transiently excited carriers on the InSb(110) surface	10 796
Henrik S. Karlsson and Ulf O. Karlsson	
X-ray standing-wave study of (AlAs) _{<i>m</i>} (GaAs) _{<i>n</i>} short-period superlattices	10 801
A. Lessmann, S. Brennan, A. Munkholm, M. Schuster, H. Riechert, and G. Materlik	
Interdiffusion in nanometer-scale multilayers investigated by <i>in situ</i> low-angle x-ray diffraction	10 811
Wei-Hua Wang, Hai Yang Bai, Ming Zhang, J. H. Zhao, X. Y. Zhang, and W. K. Wang	
Defect energy levels in electron-irradiated and deuterium-implanted 6 <i>H</i> silicon carbide	10 823
M. O. Aboelfotoh and J. P. Doyle	
Exciton-exciton scattering dynamics in a semiconductor microcavity and stimulated scattering into polaritons	10 830
F. Tassone and Y. Yamamoto	
Minibands of magnetoplasmons in semiconductor superlattices in a perpendicular external magnetic field	10 843
G. Martínez, J. H. Jacobo-Escobar, Pedro H. Hernández, and Gregorio H. Cotoletzi	
Size dependence of polaronic effects on an exciton in a spherical quantum dot	10 850
Kazunori Oshiro, Koji Akai, and Mitsuru Matsuura	
Tunneling and interferences in very small GaAs metal-semiconductor field-effect transistors	10 856
W. Poirier, D. Mailly, and M. Sanquer	
Quantizing field-induced magnetic phase in a three-dimensional electron gas	10 864
A. Gordon, M. A. Itskovsky, and P. Wyder	
Dielectric function of an electron gas under intense laser radiation in quantizing magnetic fields	10 869
W. Xu	
Bulk changes in semiconductors using scanning probe microscopy: nm-size fabricated structures	10 877
Shachar Richter, Yishay Manassen, and David Cahen	
Exciton dissociation, charge transport, and recombination in ultrathin, conjugated polymer-TiO ₂ nanocrystal intermixed composites	10 885
J. S. Salafsky	

Surface physics, low-dimensional systems, and related topics

Atomic-scale scanning tunneling microscopy of amorphous surfaces	10 895
D. E. Bürgler, C. M. Schmidt, D. M. Schaller, F. Meisinger, T. M. Schaub, A. Baratoff, and H.-J. Güntherodt	
Near-field optical spectroscopy of individual surface-plasmon modes in colloid clusters	10 903
V. A. Markel, V. M. Shalaev, P. Zhang, W. Huynh, L. Tay, T. L. Haslett, and M. Moskovits	
Ag/Cu(111) structure revisited through an extended mechanism for stress relaxation	10 910
Isabelle Meunier, Guy Tréglia, Jean-Marc Gay, Bernard Aufray, and Bernard Legrand	
Surface alloy formation of Fe on Cr(100) studied by scanning tunneling microscopy	10 918
Y. J. Choi, I. C. Jeong, J.-Y. Park, S.-J. Kahng, J. Lee, and Y. Kuk	
First-principles study of Ag adatoms on the Si(111)- $\sqrt{3}\times\sqrt{3}$ -Ag surface	10 923
Hideaki Aizawa and Masaru Tsukada	
Probing the single-wall carbon nanotube bundle: Raman scattering under high pressure	10 928
U. D. Venkateswaran, A. M. Rao, E. Richter, M. Menon, A. Rinzler, R. E. Smalley, and P. C. Eklund	
Resonant charge transfer in ion-metal surface collisions: Effect of a projected band gap in the H ⁻ -Cu(111) system	10 935
A. G. Borisov, A. K. Kazansky, and J. P. Gauyacq	
Electron promotion in collisions of protons with a LiF surface	10 950
P. A. Zeijlmans van Emmichoven, A. Niehaus, P. Stracke, F. Wieggershaus, S. Krischok, V. Kempter, A. Arnau, F. J. García de Abajo, and M. Peñalba	
Density matrix of inelastically scattered fast electrons	10 959
P. Schattschneider, M. Nelhiebel, and B. Jouffrey	
Temperature dependence of the optical response of sodium cluster ions Na _n ⁺ , with 4 ≤ n ≤ 16	10 970
Martin Schmidt, Christoph Ellert, Werner Kronmüller, and Hellmut Haberland	
Transmission and reflection in a perfectly amplifying and absorbing medium	10 980
P. K. Datta	
Analysis of the steady-state photorefractive harmonic gratings	10 985
P. Vaveliuk, B. Ruiz, and N. Bolognini	
Brownian friction of gas molecules on the graphite surface	10 992
R. D. Boutchko and L. W. Bruch	
Anharmonic adlayer vibrations on the Si(111):H surface	10 996
R. Honke, P. Jakob, Y. J. Chabal, A. Dvořák, S. Tausendpfund, W. Stigler, P. Pavone, A. P. Mayer, and U. Schröder	
Monovacancy diffusion on Ag(100), Cu(100), and Ni(100): Prefactors and activation barriers	11 014
Ulrike Kürpick and Talat S. Rahman	
Bulk modulus of C ₆₀ studied by single-crystal neutron diffraction	11 020
L. Pintschovius, O. Blaschko, G. Krexner, and N. Pyka	
Statistical thermodynamics and transport of linear adsorbates	11 027
A. J. Ramirez-Pastor, T. P. Eggarter, V. D. Pereyra, and J. L. Riccardo	
Simulations and theory of electromigration-induced slit formation in unpassivated single-crystal metal lines	11 037
Mohan Mahadevan and R. Mark Bradley	
Transition metals on the MgO(100) surface: Evolution of adsorption characteristics along the 4d series	11 047
Jacek Goniakowski	
Electromodulation of charge-transfer photoexcitations in pristine and C ₆₀ -doped conjugated polymers	11 053
M. Liess, Z. V. Vardeny, and P. A. Lane	
Resonance effects in the scattering of light from a rough metal surface with a thin coating	11 062
T. A. Leskova, E. I. Chaikina, G. Navarrete, and G. Martínez-Niconoff	
Fractal nature of π -bonded nanocrystalline clusters: A N ⁺ beam-induced phenomenon in poly(2,6-dimethyl-1,4-phenylene oxide)	11 069
A. Das, S. Dhara, and A. Patnaik	

CONTENTS - *Continued*

PHYSICAL REVIEW B

THIRD SERIES, VOLUME 59, NUMBER 16

15 APRIL 1999-II

COMMENTS

Comment on “Ground-state description of quasi-one-dimensional polarons with arbitrary electron-phonon coupling strength”	11 077
Qinghu Chen	
Cumulative Author Index	11079